



DC COMPONENTS CO., LTD.
RECTIFIER SPECIALISTS

**MBR2505W
THRU
MBR2510W**

TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER
VOLTAGE RANGE - 50 to 1000 Volts **CURRENT - 25 Amperes**

FEATURES

- * Plastic case with heatsink for Maximum Heat Dissipation
- * Diffused Junction
- * High current capability
- * Surge overload ratings - 400 Amperes
- * Low forward voltage drop
- * High Reliability

MECHANICAL DATA

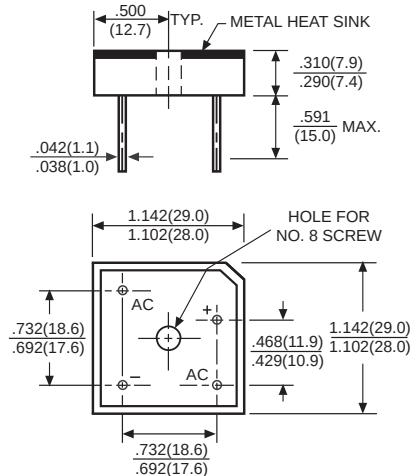
- * Case: Molded plastic with heatsink
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: MIL-STD-202E, Method 208 guaranteed
- * Polarity: As marked
- * Mounting position: Any
- * Weight: 25 grams approx.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.



MBR-25W



Dimensions in inches and (millimeters)

		MBR 2505W	MBR 251W	MBR 252W	MBR 254W	MBR 256W	MBR 258W	MBR 2510W		
	SYMBOL								UNITS	
Maximum Recurrent Peak Reverse Voltage		V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage		V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Output Current at T _c = 55°C		I _O	25						Amps	
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		I _{FSM}	400						Amps	
Maximum Forward Voltage Drop per element at 12.5A DC		V _F	1.1						Volts	
Maximum DC Reverse Current at Rated	@T _A = 25°C	I _R	10						μAmps	
DC Blocking Voltage per element	@T _A = 100°C		500							
I ² t Rating for Fusing (t<8.3ms)		I ² t	374						A ² Sec	
Typical Junction Capacitance (Note1)		C _J	300						pF	
Typical Thermal Resistance (Note 2)		R _{θJC}	2.5						°C/W	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150						°C	

NOTES : 1. Measured at 1 MHz and applied reverse voltage of 4.0 volts
2. Thermal Resistance from Junction to Case per leg.

RATING AND CHARACTERISTIC CURVES (MBR2505W THRU MBR2510W)

FIG. 1 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

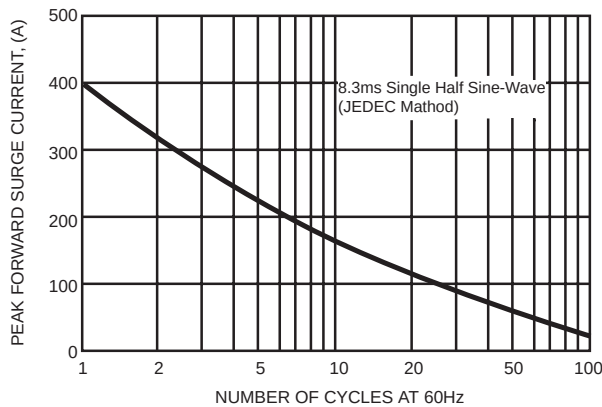


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

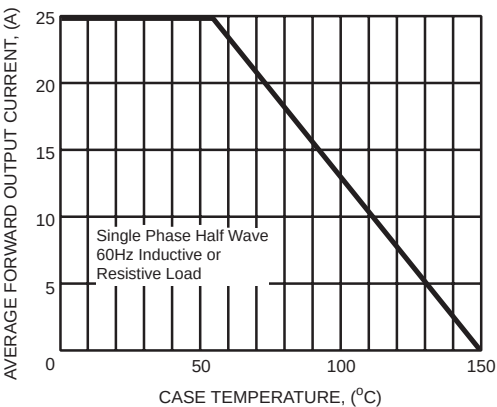


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

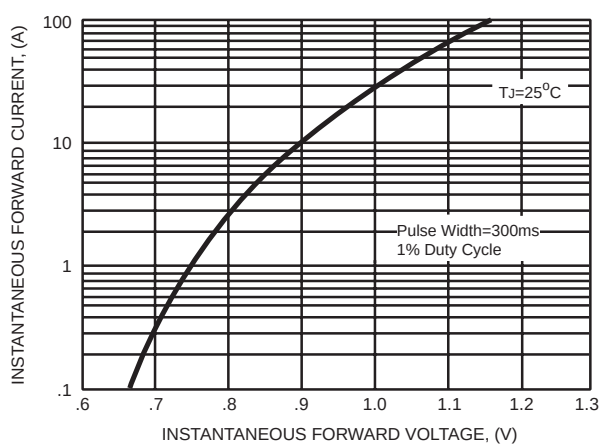
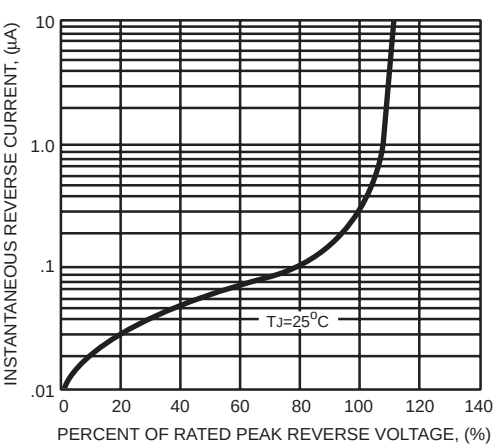


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS



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